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Challenges and approaches towards upscaling the assembly of hybrid perovskite solar cells

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In recent times, the next-generation photovoltaic technologies have accepted perovskite solar cells (PSCs) as different auspicious candidates as a result of their persistently developing efficiencies, thus attracting significant attention from both the scientific and industrial societies. Even though PSCs are dignified toward the commercial world through the photovoltaic module scale, significant challenges confusing industrialization remain. The recent efficiency of the solution-processed PSCs has reached over 25% on a laboratory scale. However, a reproducible allocation to the upscaling techniques of these processes still requires a highly controllable perovskite film formation strategy. Different coating systems such as blade coating, slot-die coating and spray coating as well as printing pathways such as screen, inkjet, and gravure printing besides vacuum deposition and laser patterning methods have been widely used as the substitutions of spin coating towards scaling up PSCs with a large area. In the current review, we have reported the practical potential of PSCs, strategies, challenges, and approaches towards the scaling up of large-area PSC modules via different deposition techniques as well as functional materials for the device architecture.

1. Introduction

Solar energy direction have been changed a lot by many researchers once the perovskite materials ($\text{CH}_3\text{NH}_3\text{PbI}_3$) investigated as a new light harvesting material for hybrid perovskite solar cells (PSCs).¹ A power conversion efficiency (PCE) of 25.2% of these kinds of solar cells was certified in 2019, which is close to that of monocrystalline silicon cells.² These perovskite materials have different features such as high absorption coefficient,^{3,4} high mobility,^{5–8} long balanced carrier diffusion length,^{7–10} and small exciton binding energy,¹¹ which make them auspicious candidates for the fabrication of these new kinds of solar cells. Besides, there are several kinds of solar cell systems similar to organic photovoltaics,¹² dye-sensitised solar cells^{13–20} and perovskite cells,^{21–26} which intent to earn the benefit of the large-scale PSC modules with low fabrication cost. PSCs with a large active area of 1 cm^2 have only achieved almost 20% in the past few years, which confirms that the upscaling of the normal active area of 0.1 cm^2 of these kinds of cells is mandatory for the future modules of these kinds of cells as the active area is considered as an important factor for the detection of the net efficiency.²⁷ The transformation of the perovskite photovoltaic technology in the sequence of “lab-to-fab” becomes a trend towards scaling up PSCs.²⁸ In fact, the active area, stability and cost of the proposed materials can be possible drawbacks for the commercial upscaling of PSCs. The active area can be affected by the series resistance of the electrodes, which results from the quality of the assembled

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layers *via* coverage and uniformity and decreases the net efficiency of the fabricated modules.^{29,30} Additionally, temperature, illumination and humidity may influence the assembled module stability deemed as a significant shortcoming of PSCs.^{31–33} Furthermore, to overcome the drawbacks encountered while using the same deposition techniques of small-area cells for upscaling, several production methodologies such as spin coating,³⁴ blade coating,³⁵ slot-die coating,³⁶ and vacuum evaporation³⁷ have been recognised to achieve large-scale and improved eminent perovskite films. Galagan and co-workers aimed to optimize the assembled modules by finding the match for active area size and PCE by studying the standard dimensions of large-area PSCs to attain good uniformity and reproducibility over the module area.^{38–42} In addition, they confirmed their experimental data using a theoretical DC simulation in order to get an appropriate matching between transparency and substrate sheet resistance. Herein, in this review, the advancements matters approved on effective large-area perovskite solar modules from the view of several fabrication technique, with studying the strategies and the challenges exist for this purpose will be covered and discussed.

2. Structural design of devices

2.1. Perovskite solar cell architectures: configurations and technical challenges

Perovskite solar cell (PSC) device configurations are mainly classified into two groups: mesoporous and planar structures with three different types: mesoporous n-i-p, planar n-i-p and planar p-i-n structures (Fig. 1).

The typical mesoporous n-i-p (PSC) architecture (Fig. 1a) includes perovskite materials that are partially or completely infiltrated in an electron transport layer (ETL) scaffold with nanoscale pores, leading to an intermixed layer. After that, the hole transport layer (HTL) is deposited on the perovskite layer, and then the structure of the assembled device is completed through evaporation of the top electrode. The photocurrent-voltage (*J*-*V*) hysteresis phenomenon in PSCs can be suppressed by enhancing charge separation using mesoporous materials.⁴³ The planar n-i-p (PSC) architecture (Fig. 1b), which has recently given high-efficiency performance with little hysteresis, is

encompassed with a compact ETL layer that attaches directly to the perovskite layer without using any mesoporous layer.^{44–46} In the current status, the existence of mesoporous materials, and sometimes HTL, in the n-i-p cell structure is not favourable for scaling up modules, as it will increase the fabrication steps.⁴⁷ Additionally, the inverted structure, p-i-n architecture (Fig. 1c), which is normally assembled with a planar structure, is coming from the inversion in the carrier extraction layers compared to the n-i-p configuration.

2.2. Perovskite solar module structures

Obviously, due to the resistance loss above the conducting electrode that may appear as a long transference expanse, the upscaling of perovskite solar modules will not be easy to attain *via* fabrication of a single PSC on a large-area substrate. Additionally, combining minor sub-cells with a series of interconnection areas, which act as the main aspect toward power loss in solar modules, can diminish the resistance loss to form a stable module (Fig. 2a).⁴⁹ The geometric fill factor (GFF) can define the photoactive area and the total area of the module ratio, and it was found that the calculation of GFF becomes essential to detect the accurate module efficiency as the module efficiency is proportionally related to the active area as well as GFF.⁵⁰ In addition, there are several steps involved in the fabrication of perovskite solar modules (PSMs).⁵¹

Furthermore, the assembled assimilated perovskite solar module design with the altered constituent arrangement is shown in Fig. 2b. It is important that the so-called balance of module (BOM) is used to protect the fabricated modules from water-induced degradation,⁵² through its components including glass plates, a sealant, a lamination film, an edge-sealing frame, a junction-box, and wiring.^{53–55} Ultimately, the upscaling fabrication of large-area cells can be summarized *via* assembling high-quality perovskite cells, combining those cells to form a module and, finally, integrating the modules into a panel (Fig. 2c).

2.3. Scalable solution deposition methods

Spin coating as well as other several deposition and printing methods such as blade coating, slot-die coating, spray coating, inkjet printing and screen-printing have been widely used in the preparation of different layers for solar cell composition. The spin coating technique is considered as the traditional way

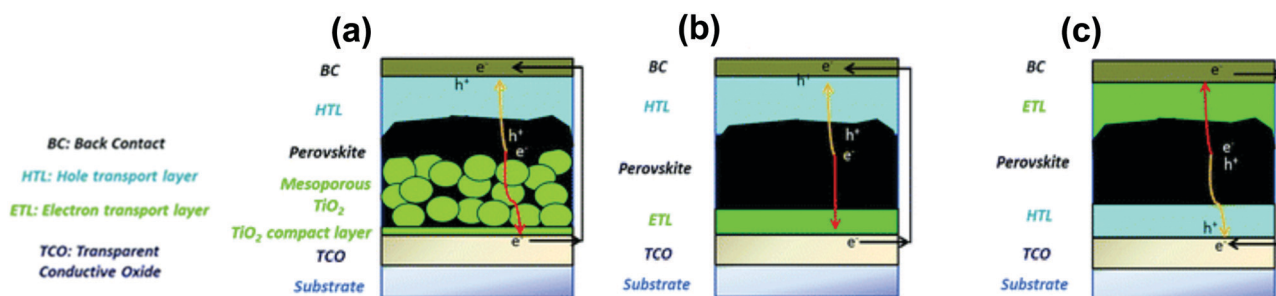


Fig. 1 Perovskite solar cell architectures: (a) n-type TiO_2 mesoporous-based; (b) planar “n-i-p”; (c) planar “p-i-n”. Illumination occurs from the substrate side. In all these cases, the substrate can be either a glass or polymer foil. Reproduced with permission from ref. 48. Copyright © 2017 The Royal Society of Chemistry.



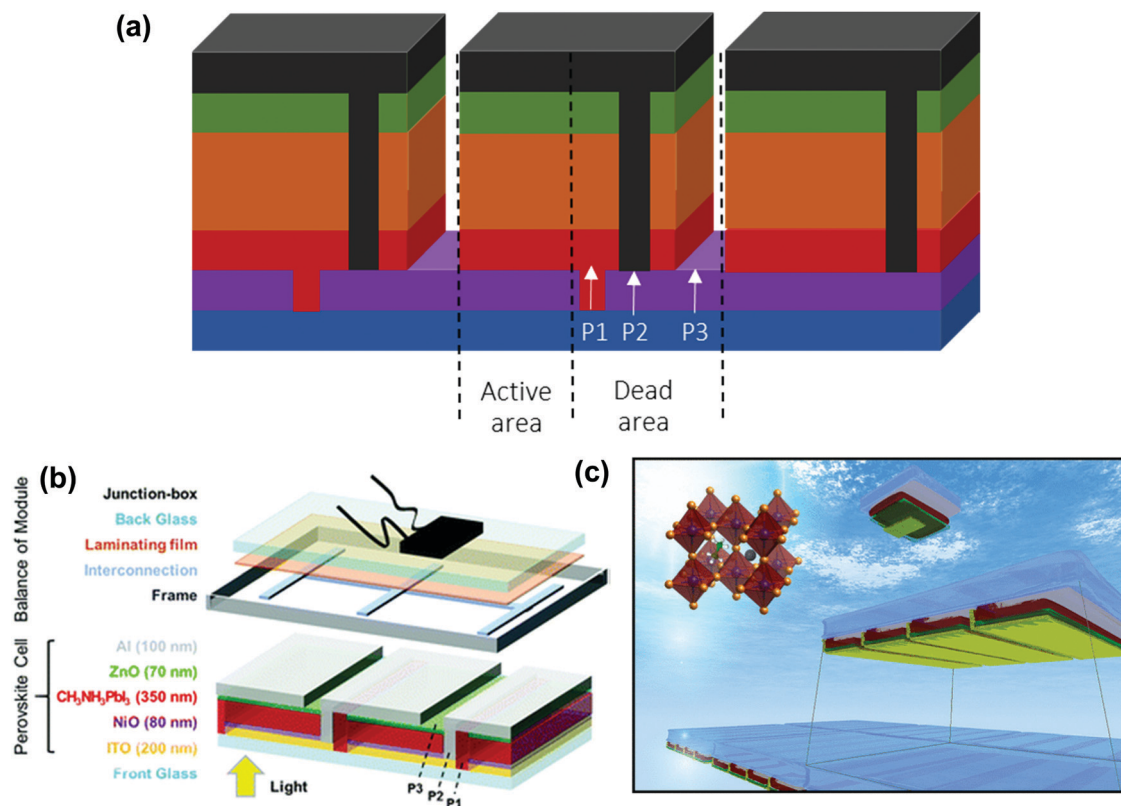


Fig. 2 Perovskite solar module architectures. (a) Interconnection of a perovskite module fabricated by typical scribing processes for thin-film solar modules. The P1 scribe separates the bottom TCO substrate, the P2 scribe provides a channel to connect the top contact of one cell to the bottom contact of the next cell to form an interconnection, and the P3 scribe isolates the top metal contact between neighbouring cells, to form cells that can be integrated into a module. (b) Structure of a monolithically integrated perovskite solar module design with different configuration layers. Reproduced with permission from ref. 55. Copyright © 2017 The Royal Society of Chemistry. (c) Up-scaling laboratory-scale perovskite solar cells to modules and panels. Reproduced with permission from ref. 51. Copyright © 2017 American Chemical Society.

for perovskite thin-film deposition. The precursor solution of perovskite materials used to fabricate the perovskite films in spin coating as well as scalable deposition methods consists of organic and lead halides, which first liquefied in organic solvents like *N,N*-dimethylformamide (DMF), dimethyl sulfoxide (DMSO) and γ -butyrolactone (GBL). Additionally, modules are made up *via* spin coating on a substrate area of about 10 cm $\times$ 10 cm but with an extensively lower PCE than their corresponding smaller area items.⁵⁶ The advantages such as thinning and smoothing gained from the spin coating method for low-area film deposition are challenging to be obtained in scalable deposition processes. Therefore, in order to fabricate PSMs by controlling the assembled films in different positions, many factors should be understandable and different other pathways must be designed for increasing the active area of PSCs. Herein, different scalable solution deposition methods and their benefits for PSC and PSM improvement are briefly studied and compared.

2.4. Coating techniques for perovskite photovoltaics

Besides spin coating, as forerunners for perovskite film deposition on a laboratory scale, several coating techniques are introduced in order to pave the way for upscaling PSCs and

obtain PSMs by controlling the quality of perovskite films deposited above large areas with high uniform layers with good crystallinity and morphology. As meticulous below, some general competing coating methodologies will be discussed to gain deep knowledge on how these techniques are used for the fabrication of PSCs and going further on the way to upscaling PSMs to accomplish the methodological necessities for industrial approach of perovskite thin films for cells and modules.

2.4.1. Spin coating. The spin coating method is considered as the common pathway to obtain large-area, highly uniform and pinhole-free perovskite films for laboratory-scale PSCs, which paves the way for the use of the spin coating technique to attain stable perovskite solar modules with large area and high efficiency as well as stability.⁵⁷ The benefits and advantages behind that exhausting technique of deposition are to accomplish different uniform layers with high film thickness and high reproducibility, which achieved different controllable parameters with ink formulation. In addition, the top efficiency recorded for the small-laboratory-scale cells fabricated *via* the spin coating pathway, with an active area of almost 0.1 cm², was higher than that of the others with a large area with an active area ≥ 1 cm².⁴² The diminution in efficiency, which is considered as one of the most important disadvantages of this



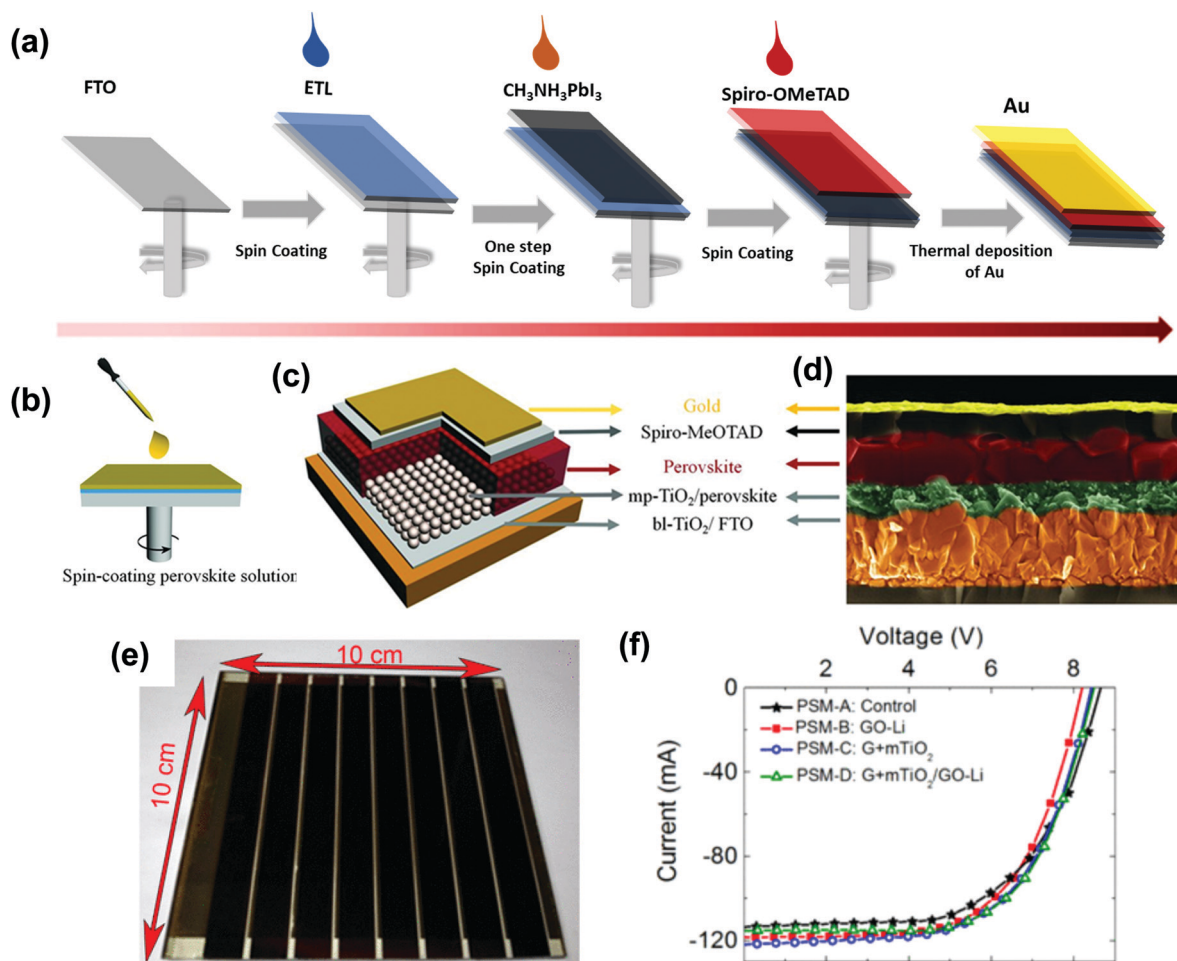


Fig. 3 Perovskite film deposition and device structure. (a) Schematic of perovskite solar devices step by step. (b) Schematic showing the spin coating of the perovskite solution on the substrate. (c) Schematic of the perovskite solar cell configuration, where a smooth and compact perovskite capping layer fully covers the mesoporous TiO_2 layer (mp-TiO_2) infiltrated with perovskites. (d) A high-resolution cross-sectional SEM image of a complete perovskite solar cell with large area fabricated by the spin coating technique. (b–d) Reproduced with permission from ref. 61. Copyright © 2016 SpringerNature. (e) Photograph of the large-area perovskite solar module (50 cm^2 active area). (f) Current–voltage (I – V) characteristics of tested modules (i.e., PSM-A, PSM-B, PSM-C, and PSM-D). All the I – V measurements refer to the encapsulated devices. (e and f) Reproduced with permission from ref. 62. Copyright © 2016 American Chemical Society.

technique, comes from the difficulty in controlling the deposition of different layers *via* spin coating in case of the large area, which affected the uniformity as well as the crystallinity of the assembled layers.^{58,59} Furthermore, Yang *et al.*⁵⁹ attained a PCE of 16.3% with a stabilized output of 15.6% in $\text{CH}_3\text{NH}_3\text{PbI}_3$ perovskite-based cells on an active area of 1.2 cm^2 . In addition, with a spin-coated perovskite layer, Qiu *et al.*⁶⁰ apprehended a module with a PCE of 13.6% over an orifice area of 4 cm^2 .

The fabrication of different layers of perovskite cells or modules by the spin coating technique is illustrated in Fig. 3a. In addition, to assemble perovskite solar cells, the conductive electrode (FTO) was etched to obtain the anticipated pattern, and then an ETL of TiO_2 was deposited *via* the spin coating pathway. After that, the perovskite layer and the HTL were deposited layer by layer above TiO_2 by the spin coating technique and finally the cell was obtained by thermal evaporation of Au on the top. The schematic of the spin coating process

of the perovskite solution on the substrate surface is shown in Fig. 3b. Either the perovskite cells or modules can be fabricated by the spin coating technique, which considers being one of the essential pathways to deposit the main constituent layers.⁶¹ Additionally, the schematic design of the perovskite solar cell arrangement, where a smooth and compact perovskite capping layer fully covers the mesoporous TiO_2 layer (mp-TiO_2) subverted with perovskites, is shown in Fig. 3c. The mesoscopic-planar bilayer device architecture with a cross-sectional SEM image is illustrated in Fig. 3d to affirm the alteration in morphology between films in the fabricated cell.⁶¹

One of the latest studies that concern about the production of perovskite modules with large active area by the spin coating technique was done by Di Carlo *et al.*⁶² They established large-area perovskite solar modules (PSMs), assembled on a $10 \times 10 \text{ cm}^2$ substrate area, comprising eight series of joined PSCs (active area 6.32 cm^2), with different interfaces and an overall



active area of 50.56 cm² (Fig. 3e), with *I*-*V* characteristics (Fig. 3f), paving the way for the industrial exploitation of graphene/perovskite solar cells (PSCs).

2.4.2. Doctor blade coating (blade coating). The blade coating technique (Fig. 4) is a simple and cheap printing choice, considered as a convenient pathway for incessant construction with roll-to-roll operations, leading to fully printable devices on both glass and flexible substrates, wherein the blade is immobile and flexible substrates on a roller are in motion to attain PCE > 19%.⁶³ Mallajosyula *et al.*⁶⁴ reported deposition of perovskite island films with large grain sizes *via* one-step blade coating above large-area substrates. Furthermore, one of the advantages of the blade coating technique while using continuous roll-to-roll deposition is that the ink waste is substantially reduced compared with the spin coating technique, which resulted in the deposition of homogeneous thin films with a controllable thickness.

As any other technique that has advantages and disadvantages, the blade coating technique can show some disadvantages which come from controlling the gap between the blade and the substrate. The disadvantages can be overcome by monitoring the blade geometry as well as its speed, in addition to the viscosity of the ink and the substrate wettability.

The main target to obtain either small-area PSCs or large-area PSMs is to assemble high-quality large-area perovskite layers that is secure from the doctor blade coating technique as illustrated in Fig. 4.⁶⁵ To follow the procedure for film assembly *via* the blade coating method, a solution of appropriate concentration is added to the substrate and the doctor blade is moved at an optimized speed of 1.0 cm s⁻¹ to form a contact line (Fig. 4a and b).⁶⁵ The aggrandize structure of contact line is shown in Fig. 4c.⁶⁶ By reason of the *in situ* thermal annealing of the substrate, the solvent evaporates very rapidly and forms the perovskite film (Fig. 4d and e).⁶⁵

2.4.3. Inkjet printing and slot-die coating. Inkjet printing in addition to slot-die coating is considered as an auspicious method to assemble and scale up perovskite solar modules manufactured on a large scale. On one hand, in inkjet printing, nozzles, with droplet size control, are the source to disperse the precursor ink (Fig. 5a). Different studies confirm the suitability of inkjet method to fabricate both small- and large-area solar cells with respect to the printing speed and device structure to get large areas of perovskite modules, which is considered as an important advantage of that technique.⁶⁷ On the other hand, slot-die coating (Fig. 5b) is similar to blade coating and uses a reservoir of ink with a thin slit to spray ink over the substrate that is also considered as an advantage for both techniques.⁶⁸

Comparing slot-die coating with other deposition methods like blade ones, although it need more amount of inks, which is considered as a disadvantage of that technique, it shows better yield and reproducibility for the fabricated layers with uniform surface, good morphology and crystallinity.^{69–71} Inkjet printing as well as slot-die is an auspicious printing pathway to develop the assembly of PSCs with a scale up range for up to 51 cm² active area, and can be predominantly significant even for roll-to-roll manufacturing in the future.^{72–75} The cross-section SEM of the fabricated perovskite solar cell based on TiO₂ nanoparticles, by the coating technique, is illustrated in Fig. 5c.⁷⁶

Scalable fabrication of PSCs depending on TiO₂ nanoparticles deposited by inkjet-printing as well as slot-die methods exhibits high PCE (measured in backward and forward directions) compared to the samples attained by the spin coating technique as shown in Fig. 5d and f. Likewise, PCE at a persistent voltage up to the maximum power point (MPP) was checked for both devices (Fig. 5e and g).⁷² The good results obtained for the different cells with two techniques confirm the possibility to use these techniques for large-scale fabrication and can open up a new pathway for all inkjet (or slot-die)-printed PSCs.^{76–79}

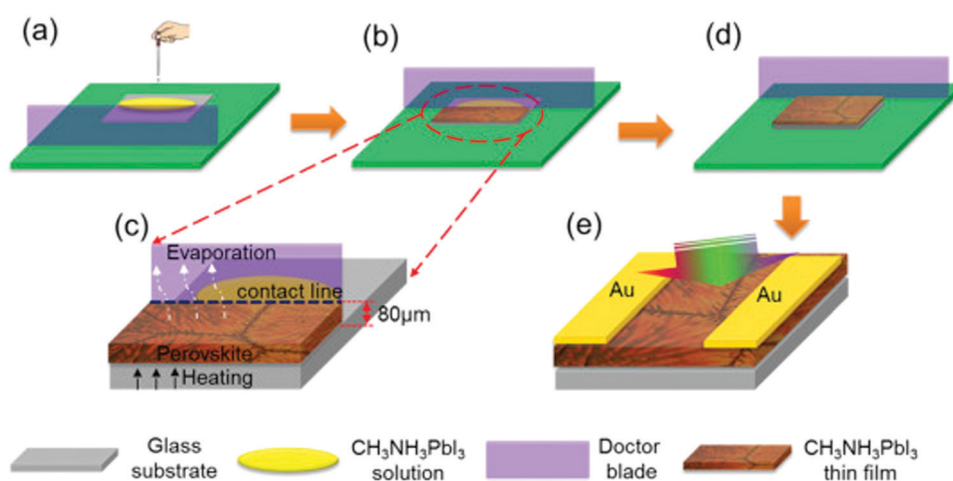


Fig. 4 Schematic of *in situ* doctor blade coating technique for fabricating CH₃NH₃PbI₃ films. (a) CH₃NH₃PbI₃ solution (550 mg ml⁻¹) is dropped before the doctor blade closes the substrate. (b) CH₃NH₃PbI₃ crystal nucleate and growth during doctor blade coating. (c) Magnified schematic in (b). (d) CH₃NH₃PbI₃ crystal film is growing with the moving of doctor blade and a large-area CH₃NH₃PbI₃ film can be formed on the substrate. The substrate is *in situ* heated to 100–140 °C. The spacing between the doctor blade and the substrate is 80 μm. (e) Schematic of a CH₃NH₃PbI₃ photodetector fabricated *via* doctor blade coating. The illumination light source irradiates from the front side of electrodes. Reproduced with permission from ref. 65. Copyright © 2017 Elsevier.



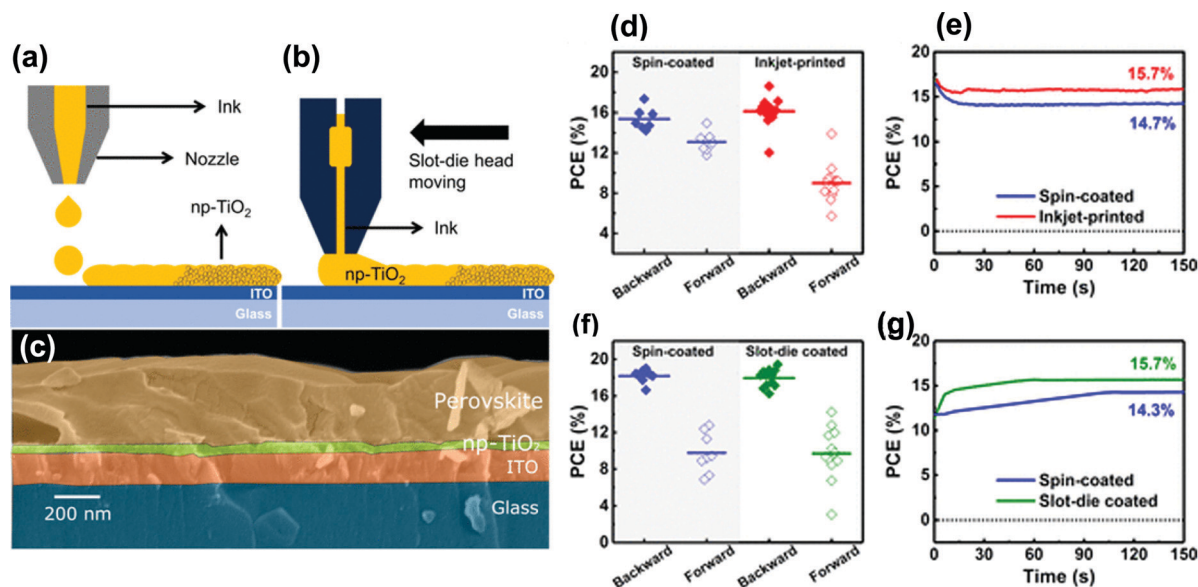


Fig. 5 Schematic of (a) inkjet printing and (b) slot-die coating of the np-TiO₂ ETL is shown with the respective power conversion efficiencies of perovskite solar cells, fabricated on top of these layers in panels (d) and (f). (c) The cross-section SEM of the assembled perovskite solar cell. PCEs measured at a constant voltage near the maximum power point under AM1.5G illumination are represented in panel (e) and MPP tracking in panel (g) for 150 s. Blue, red, and green represent PCEs of PSCs fabricated with spin-coated, inkjet-printed, and slot-die-coated np-TiO₂ ETL, respectively. Reproduced with permission from ref. 76. Copyright © 2018 American Chemical Society.

2.4.4. Spray coating. In different spray coating types, high-quality films are obtained using a nozzle that intersperses tiny liquid droplets above substrates (Fig. 6a).^{80–82} In order to improve the spray-coated technique for PSC fabrication, Barrows *et al.* consummated the first study in 2014, showing an efficiency of 11.1% for the assembled cells.⁸³ Several parameters, which affect the deposition method and are considered as a necessary factor for the realization of the absorber layer, such as substrate temperature, volatility of the coating solvent and post annealing temperatures were studied.^{84–86} In 2016, and for the first time, Das *et al.* showed the potential to fabricate PSCs on flexible substrates *via* roll-to-roll processing with an efficiency of almost 8.1%, through spray-coated perovskite absorbers.⁸⁵ Later, using two-step spray

coating method, Hunag *et al.* succeeded to increase the homogeneity of the absorber deposition and enhance the spray-coated PSCs' net PCE to 16.0%.⁸⁷ Then, the highest PCE for spray-coated PSCs was reported to be 18.3% by the study of Heo *et al.*, *via* optimizing the solvents' boiling point for governing the solvent evaporation and doing different characterizations of the assembled cells (Fig. 6b–d).⁸⁸ As a result of the most studies concerned about the spray coating technique, the assembling of 100 cm² large PV modules *via* 40 cm² active area and the comprehended PCE of the fabricated modules was almost 15.5%.⁸⁸

In summary, to upscale the perovskite thin-film layers, spray coating is considered as an appropriate pathway towards that achievement. Diverse parameters like precursor, solvents,

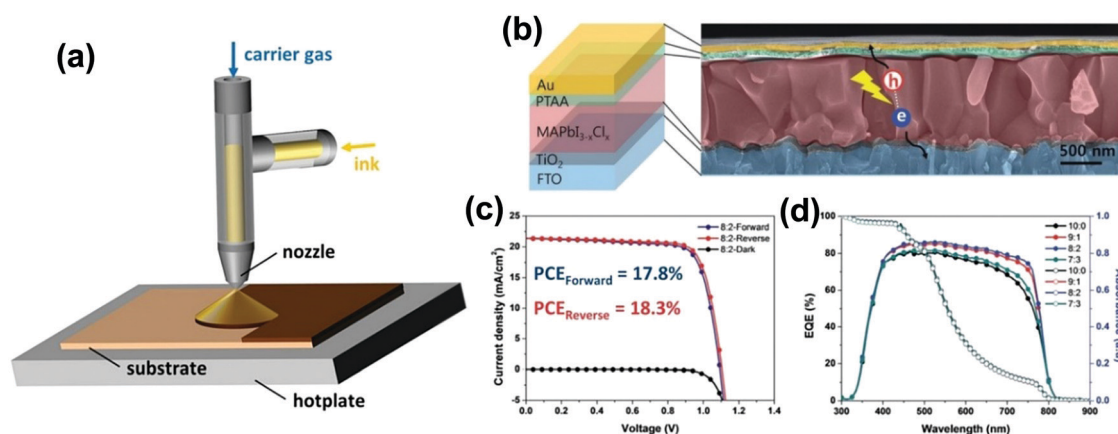


Fig. 6 Spray coating. (a) Schematic of the spray coating process. (b) SEM cross-sectional image of a high-quality spray-coated MAPbI_{3-x}Cl_x perovskite absorber. (c) PCEs up to 18.3% in reverse J–V characteristics and (d) high external quantum efficiency (EQE) were achieved, which is a result of a careful solvent engineering of the spray process. Reproduced with permission from ref. 91. Copyright © 2019 WILEY-VCH.

nozzle spray angle, the scanning speed, and the flow rate considered as advantages of that technique should be controlled for an attainable extraordinary throughput assembly and controlling the quality of perovskite thin films.^{89–91}

2.5. Printing techniques for perovskite photovoltaics

In addition to the different coating techniques used to assemble both perovskite solar cells and perovskite solar modules, there are several printing and patterning techniques that illustrate effective potential toward attaining cells as well as modules in a good manner. The several printing pathways are presented to pave the way for upscaling PSCs and obtain PSMs controlling the quality of perovskite films deposited above large areas with a high uniform layer with good crystallinity and morphology. In the next section, some general competing printing methodologies will be discussed to gain deep knowledge on how these techniques are used for the fabrication of PSCs and going further on the way to upscaling PSMs to accomplish the methodological necessities for industrial approach of perovskite thin-films for cells and modules.

2.5.1. Screen printing. In screen-printing, the technique is dependent on holding the patterned mesh screen and transfer ink to the substrate. For these kinds of printing techniques, it is possible to attain fully printed PSCs with improvement of mesoporous layers to fabricate stable and enhanced devices.^{92–95} In 2017, Han *et al.* succeeded in fabricating and studying perovskite solar modules (PSMs) with the configuration structure of FTO/compact-TiO₂/(meso-TiO₂/meso-ZrO₂/meso-carbon)/perovskite,^{96,97} with a 100 cm² substrate and an active area of 49 cm², by the screen-printing technique by connecting 10 subcells serially in monolithic architectures to allow reproducible production. The module fabrication and architecture were presented schematically and as image (Fig. 7a and b).⁹⁸ In addition, the energy level diagram of the fabricated devices, with barriers, to block the recombination of electrons with holes is shown in Fig. 7c. It can be noticed that, when the light illuminates, charge separation occurred as the electrons are transferred in the electron transport layer (ETL) direction and the holes directed to the hole transport layer (HTL) position, to TiO₂ and carbon, respectively, and after that to the electrode.⁹⁸ Along these lines, the disconnected carriers can be transported *via* serially connected PSMs as shown in Fig. 7d, after that, they are extracted to the external circuit.⁹⁸

For the future prospects of that technique, most of the assembled devices exhibit up to 10% efficiency as well as long-term stability, which is considered as an advantage and also confirms the possibility of achieving the fully printable perovskite solar modules and put that kind of upscaling in the roadmap to efficacious commercialization of perovskite solar cells.^{99–101} A fully printable perovskite solar panel with 7 m² area was fabricated as a first step in the direction of practical photovoltaic tender, as shown in Fig. 7e. Finally, each of the 1 m² panels was accumulated *via* 96 PSMs and controlled modules with several numbers of sub cells. The assembled modules can be enhanced *via* an emerging auto production line, permitting incessant and manageable assembling process of the module (Fig. 7f).⁹⁸

2.5.2. Laser patterning. Laser system processing purposes to pattern or remove each layer in the perovskite cell configuration and avert any damage happening to the conductive (TCO) substrate.¹⁰² Spyropoulos *et al.* fabricated the perovskite solar modules by a laser patterning method which effectively suppress the hysteresis.¹⁰³ Fig. 8a and b illustrate the schematic diagram as well as the cross-section SEM of the fabricated module with different layers. The *J*–*V* performances of perovskite solar cells determined by the evaporation method, laminated contacts and the consistent perovskite module are obtained from Fig. 8c.¹⁰³ Use of a laminated electrode in that study confirmed that the average efficiency is decreased owing to the loss of *J*_{sc} and FF by 11%, which is matching to the previous studies, while *V*_{oc} remains almost unchanged due to the optical interference gained *via* the EQE spectra for wavelengths > 550 nm.^{104–107} Outstandingly, the top electrode roll lamination was originally established to adapt as working thin-films for PSC and PSM technologies, which opens up a completely novel opportunity for the economic assembly of organic and hybrid electronic utilizations.^{103–105}

2.5.3. Roll-to-roll (R2R) compatible deposition. R2R, with compatible parameters to different printing techniques, has been investigated to fabricate large-scale, low-cost devices and modules with high reproducibility.^{108–113} The material (A), chemical (B), and process (C) engineering indispensable to accomplish scaled-up PSC manufacture are delineated in Fig. 9. Bromide and formamidinium (FA), as perovskite materials (Fig. 9a), have been magnificently amalgamated inside the CH₃NH₃PbI₃ lattice to alleviate *J*–*V* hysteresis¹¹⁴ and eradicate fundamental thermodynamic instability.¹¹⁵

Through the R2R coating pathway and to optimize the CH₃NH₃PbI₃ growth and obtain module-scale PSCs, different parameters of perovskite compositional engineering such as the microstructure and composition are considered as essential steps in that study (Fig. 9b).¹¹⁶ The extreme operative approach to regulate development thus turn out to be tuning the thermodynamics driving advance over and done with precursor solution composition,¹¹⁷ chemistry of the surface on which progression happens,¹¹⁸ annealing environments, and atmosphere in the course of progress.^{119,120} Solution additives and solvent engineering possibly will affect the morphology and film quality, which create interface adaptation as significant contemplation in scale-up notwithstanding the challenge of film deposition by the R2R pathway.¹²⁰

Furthermore, the piercing restrictions to PSC market prospective may come from thermal and ambient instabilities, which push the impending price as well as flexible PSCs to be enhanced towards the technology's existing capability intended for commercialization (Fig. 9c).¹¹⁶

2.6. Large-area fabrication techniques for modules

Numerous techniques such as chemical vapour deposition (CVD), vapour-assisted sequential processing and vacuum-solid reaction (VSR) considered as promising pathways compared to the other above-mentioned deposition techniques were used to fabricate solar modules with large area and long-term stability.¹²¹



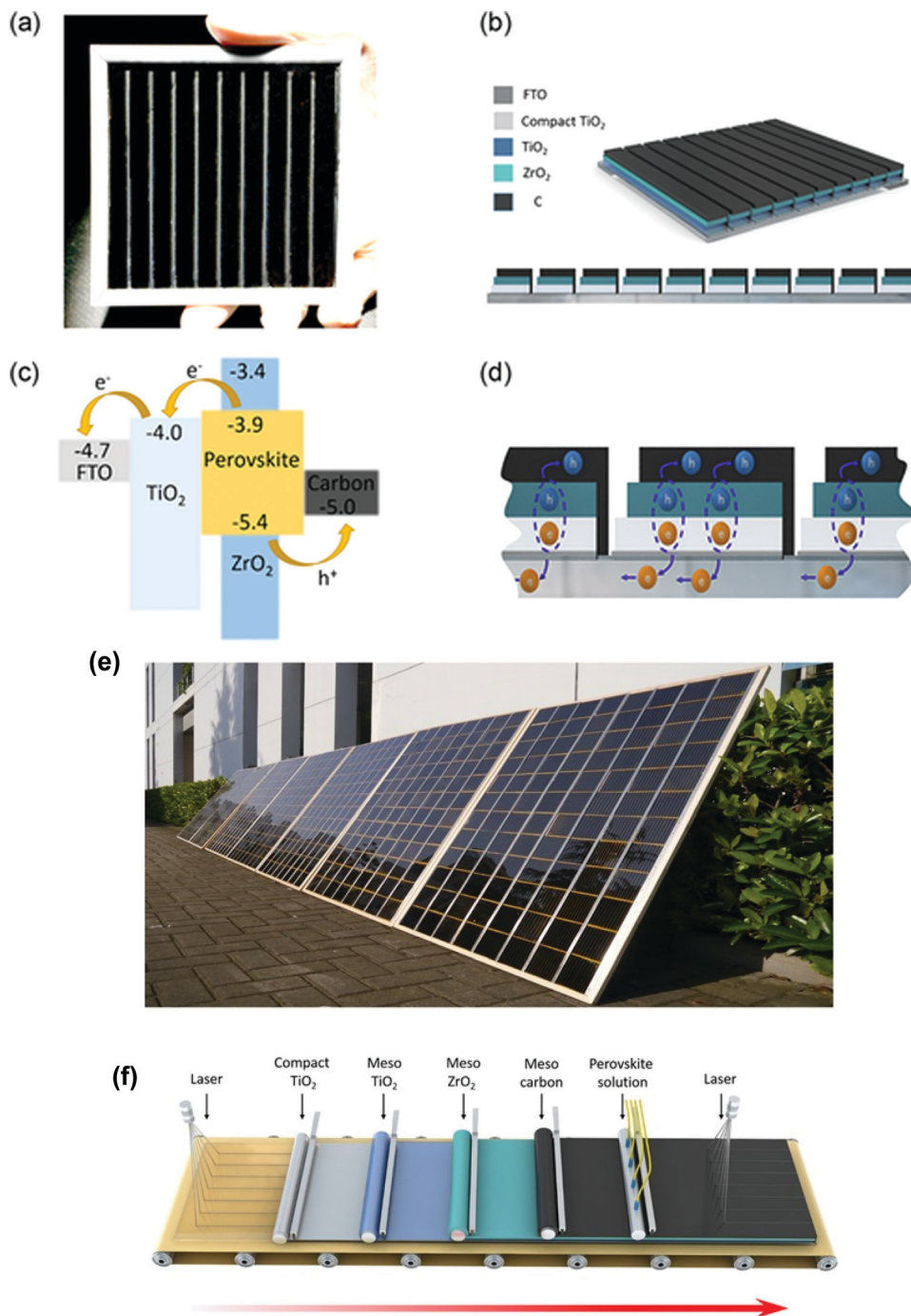


Fig. 7 (a) Image of a monolithic printable PSM with 10 subcells. (b) The monolithic interconnection scheme of the module. (c) Energy level diagrams of the hole-conductor-free printable PSC. (d) Schematic of the electron and hole separation on a serially connected PSM. (e) Image of 7 m² printable perovskite solar panels. (f) Schematic of the proposed production line of PSMs. Reproduced with permission from ref. 98. Copyright © 2017 WILEY-VCH.

In order to attain perovskite modules with high efficiency and long-term stability, different parameters should be considered like the post annealing process to get homogeneous substrates with large crystals and pinhole free surface.¹²² Most of the vacuum deposition methods are focused to obtain different layers with promising features towards upscaling of cells in the direction of large-active-area perovskite modules.^{123–125}

2.6.1. Large-area flexible devices. Di Giacomo *et al.*¹²⁶ have breakthrough the normal studies, which concern about the laboratory-scale flexible perovskite cells, and fabricated the first flexible perovskite solar module. In that work, they succeeded to attain fully printed flexible cells *via* deposited perovskite and HTL layers with spin coating, in addition to obtaining the back electrode *via* evaporation¹²⁷ or screen printed techniques.¹²⁸ In addition, Hwang *et al.* actually explained the process to a



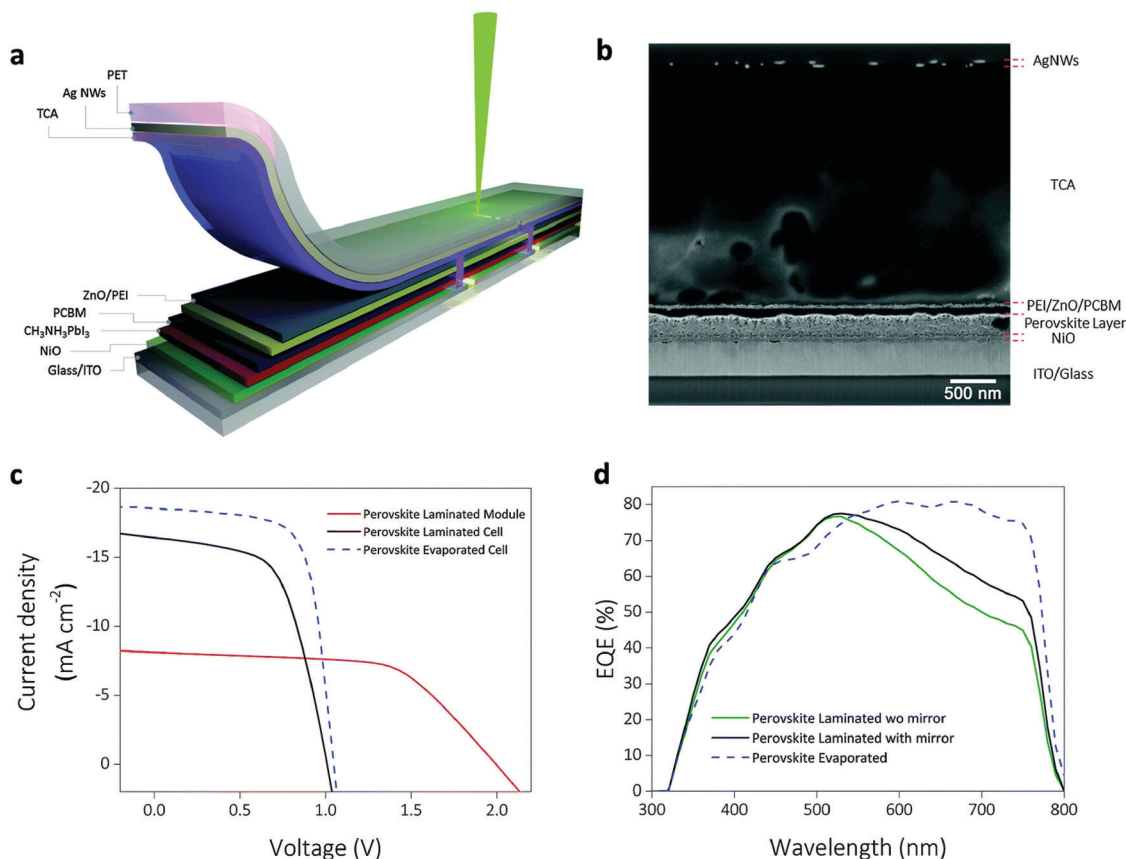


Fig. 8 (a) Device architecture of laminated perovskite solar cell/module. (b) Cross-section scanning electron microscopic image of a laminated perovskite solar device on a glass substrate. (c) J - V characteristics of perovskite solar cells and modules with laminated top electrode. (d) EQE spectra of reference perovskite solar cell with 100 nm evaporated Ag top electrode (blue dashed line), laminated perovskite solar cells measured with reflecting mirror in the back (black line), and laminated OPV cell measured without reflecting mirror (green line). Reproduced with permission from ref. 103. Copyright © 2016 The Royal Society of Chemistry.

roll-to-roll printer, as shown in Fig. 10a.¹²⁹ Additionally, 3D printing was used to prepare a simple air blade that targeted to form high-quality glassy PbI_2 layer, which moved after that into a roll that acts as a small chamber to be then rehabilitated to cloudy PbI_2 . The layer was then easily transformed to a perovskite layer by slot die coating. Through that study, and by optimizing of roll-to-roll pathway, it shows an acceptable tendency to be used for the fabrication of large-scale modules in the future.¹²⁹

Additionally, a photo of the printed perovskite module on a $10\text{ cm} \times 10\text{ cm}$ substrate is illustrated in Fig. 10b, showing that the module has 5 cells in series connection and each cell has 8 cm^2 of active area. Furthermore, I - V curves of the roll-to-roll printed perovskite module on ITO/PET and lab-scale printed perovskite solar cells on an ITO glass substrate are shown in Fig. 10c.¹²⁹

2.6.2. Vapour-phase deposition. A number of methods like physical vapour deposition (PVD), sputter coating, chemical vapour deposition (CVD), and atomic layer deposition (ALD) as a representative for deposition pathways *via* vapour, which acts as a substitution to solution-based coating methods for perovskite films in order to accomplish large-scale modules.

Furthermore, Borchert *et al.* fabricated solar cells with an efficiency up to 14.2% through vapour-deposited layers, which paves the way in the direction of large-area stable perovskite modules.^{130–132}

Furthermore, the schematic diagram in Fig. 11a illustrates the normal working distance in between the thermal sources and the rotating substrate in the evaporation system techniques that was found to be almost 20 cm.¹³³ Regarding that distance as well as the radius of the system chamber, the thickness of the formed films will be affected and the center of the substrate will be much thicker compared to the rest of the substrate. In addition, the obtained film *via* deposition and after annealing can confirm through a photograph illustrated in Fig. 11b. Additionally, in order to attain both the surface roughness and surface coverage of the deposited film over an area of $5\text{ }\mu\text{m} \times 5\text{ }\mu\text{m}$, the atomic force microscopy (AFM) is considered as the best option to gain that important knowledge (Fig. 11c).¹³³ The obtained data indicate that the surface roughness of the gained film is almost $R_{\text{RMS}} = 6.2\text{ nm}$, which confirms the formation of homogeneous, little light scattering and very smooth layer, with no pinholes films, as checked from all the image area.^{133–136} The gained value for that film, obtained *via* a



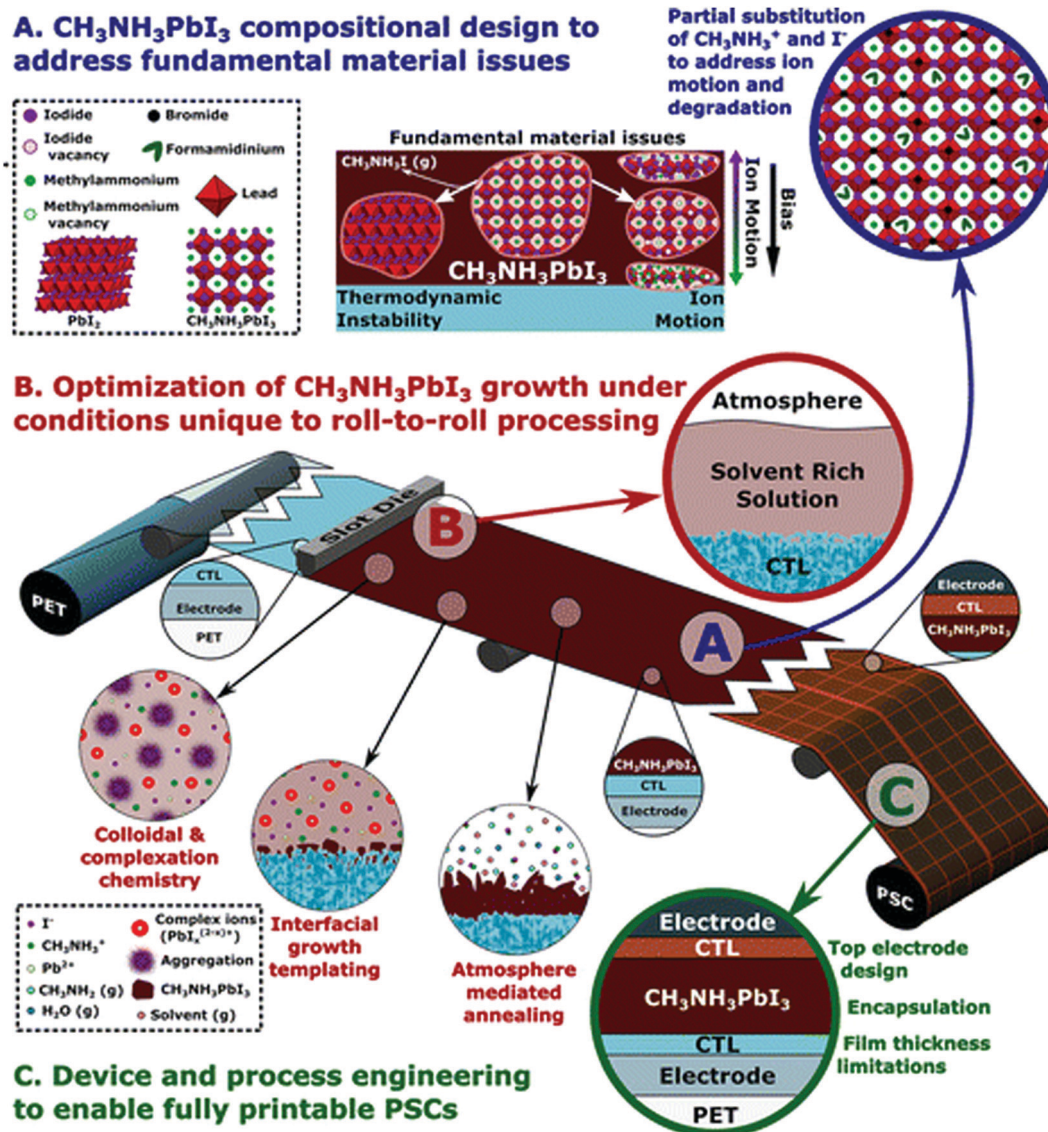


Fig. 9 Summary of research directions necessary to fuel PSC technological translation by slot-die R2R coating. (A) Material engineering can address intrinsic ion diffusivity and degradation of $\text{CH}_3\text{NH}_3\text{PbI}_3$, (B) optimization of perovskite growth under R2R conditions is necessary to reach performance requirements, and (C) device engineering is required to extend the device life and expand the material toolbox for the PSC design. Reproduced with permission from ref. 116. Copyright © 2016 American Chemical Society.

vapour deposition technique has a lower value of roughness compared to the value obtained for other materials like FAPbI_3 , with described roughness values ranging from 18 nm^{134} to above 100 nm^{135} . Moreover, scanning electron microscopy (SEM) as well as scanning transmission electron microscopy (STEM) is considered as a faultless tool to detect the actual morphology and give acceptable study regarding the crystal quality of the formed films for the solar cell devices. A uniform film of FAPbI_3 , with no observable pinholes, can be exposed from the typical cross-sectional SEM image (Fig. 11d).^{136–138} However, STEM was found as an important tool for observing the crystal quality and interfaces of the fabricated devices *via* detecting the cross-sectional images of these device. The data gained from Fig. 11e confirms the crystallites of different

orientations within the perovskite film, with some extending vertically in different positions of the film. Other issues can be confirmed *via* the STEM image, which is the high contrast between the FAPbI_3 (bright) and the carbon-rich (dark) C_{60} and spiro-OMeTAD that surround it.

3. State-of-the-art results for modules

Compared to the state-of-the-art PCEs for spin-coated PSCs, which reached recently almost 25.2%,² the PCEs of PSMs handled *via* scalable solution deposition procedures examined in the current review show less state-of-the-art records due to less optimization and control the engineering of those



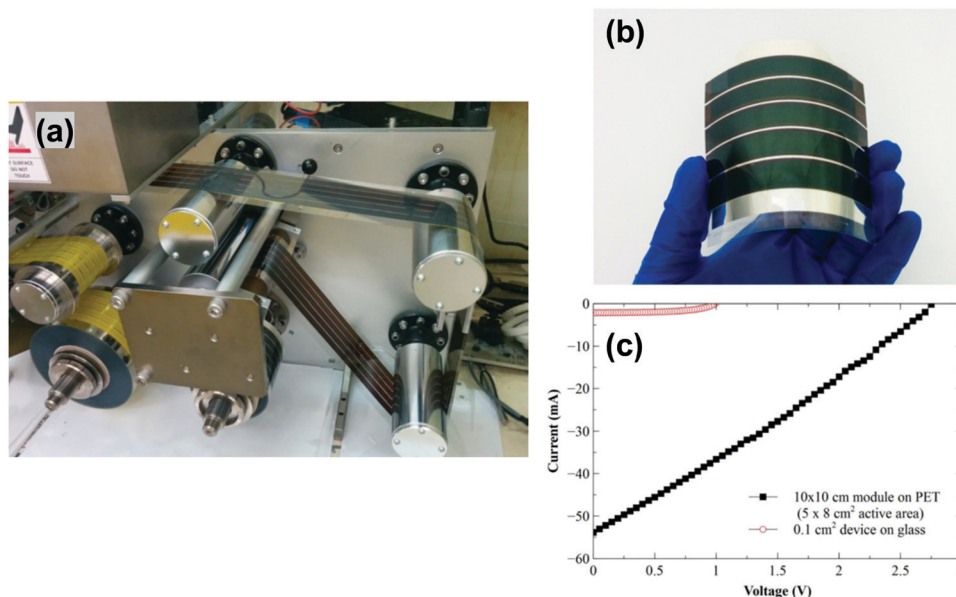


Fig. 10 Roll-to-roll production of flexible perovskite solar cell module. (a) Roll-to-roll converted perovskite film from the cloudy PbI_2 layer. (b) A photo of the printed perovskite module on a 10 cm $\times$ 10 cm substrate. The module has 5 cells in series connection and each cell has 8 cm² of active area. (c) I - V curves of roll-to-roll printed perovskite module on ITO/PET and lab-scale-printed perovskite solar cells on ITO glass. Reproduced with permission from ref. 129. Copyright © 2015 WILEY-VCH.

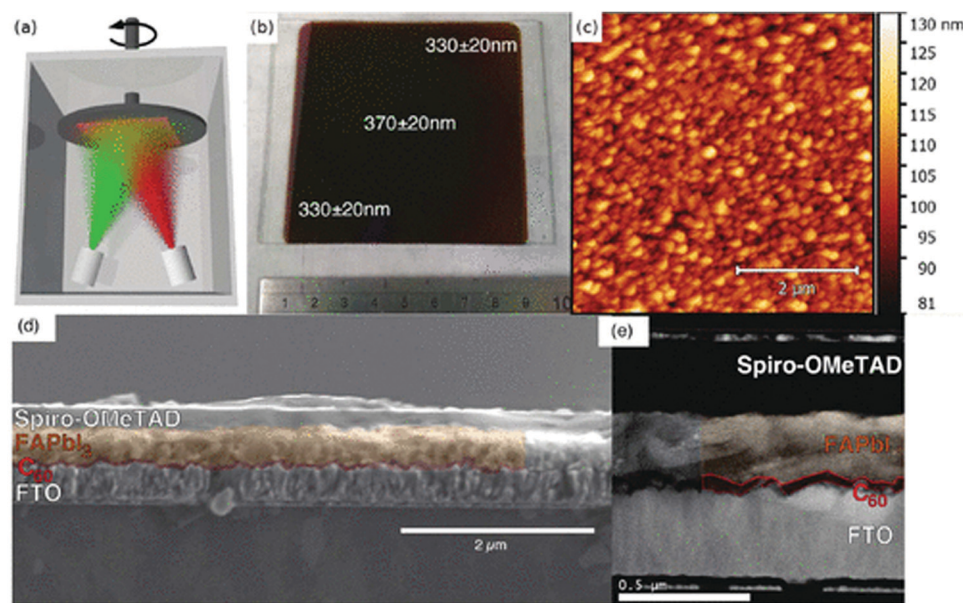


Fig. 11 (a) Schematic of the dual-source co-evaporation system used in this study. (b) Photograph of a 8 cm $\times$ 8 cm thin film of FAPbI_3 deposited on a glass substrate. The image shows the substrate after thermal annealing at 170 °C for 1 min. The results of thickness measurements at three positions are superimposed on the image, and a metal ruler with a centimetre scale is shown as a size reference. (c) Atomic force micrograph of a 5 μm $\times$ 5 μm region of the sample. The surface was found to be very smooth with a root-mean-square roughness $R_{\text{RMS}} = 6.2 \text{ nm}$. (d) A scanning electron microscopic image and (e) a scanning transmission electron microscopic image of a full FAPbI_3 solar cell. From the bottom, the layers are a glass substrate; a fluorine-doped tin oxide (FTO) layer, a thin C_{60} layer, a FAPbI_3 layer, a spiroOMeTAD layer, and the silver electrode. Reproduced with permission from ref. 133. Copyright © 2017 American Chemical Society.

techniques. In Table 1, the contemporary accomplishments for coating pathways, different parameters related to the fabricated modules including perovskite structure, J - V -characteristics, solar cell area, modules area and PCEs are summarized. Intended for numerous deliberated scalable deposition methods (blade

coating, slot-die coating, inkjet printing, and spray coating), the first approach was reported 5 years ago.¹³⁹ However, the researchers started to focus on the upscaling of perovskite solar cells toward attaining PSMs, the enhancement of scalable solution-based deposition pathways lateness a lot if it is

Table 1 Several studies on perovskite solar modules (PSMs) employing the series interconnections with different cells and with total areas more than 10 cm²^a

Perovskite fabrication method	Perovskite structure	Active area (cm ²)	Module area (cm ²)	Number of cells inter-connected	PCE ^b (%)	J_{sc} ^b (mA cm ⁻²)	V_{oc} (V)	FF (%)	Ref.
Spin coating	MAPbI ₃	60	100 (10 × 10)	10	8.7	1.9	8.1	57	140
Spin coating	MAPbI _{3-x} Cl _x	16.8	25 (5 × 5)	5	5.1	2.0	4.3	60.3	141
Spin coating	MAPbI ₃	40	100 (10 × 10)	10	12.9	2	10.1	63.7	142
Spin coating	CH ₃ NH ₃ PbI _{3-x} Cl _x	10.8	32.5 (5.7 × 5.7)	4	10.5	5.3	3.37	56	143
Spin coating	CH ₃ NH ₃ PbI _{3-x} Cl _x	7.9	31.4 (5.6 × 5.6)	4	3.1	5.2	3.4	71	144
Spin coating	MAPbI ₃	10.1	32.5 (5.7 × 5.7)	4	13	4.7	4.2	66.5	145
Spin coating	MAPbI _{3-x} Cl _x	3.64	9 (3 × 3)	4	13.6	19.1	0.9/cell	75	146
Spin coating	CH ₃ NH ₃ PbI _{3-x-y} Br _x Cl _y	25.2	100 (10 × 10)	9	14.3	2.1	9.1	74.4	147
Spin coating	MAPbI _{3-x} Cl _x	15 (GFF ~ 0.6)	25 (5 × 5)	8	12	2.6	8	58.2	148
Spin coating	MAPbI ₃	11.25	25 (5 × 5)	5	15.4	4.3	4.7	77	149
Spin coating	MAPbI ₃	50.6	100 (10 × 10)	8	12.6	2.3	8.6	64.6	150
Spin coating	MAPbI _{3-x} Cl _x	12	25 (5 × 5)	3	11.2	6.5	2.7	63.8	151
Spin coating	K _{0.03} CS _{0.05} (FA _{0.85} MA _{0.15}) _{0.92} -Pb(I _{0.85} Br _{0.15}) ₃	20	36 (6 × 6)	6	15.6	3.5	6.8	65	152
Spin coating	K _{0.03} CS _{0.05} (FA _{0.85} MA _{0.15}) _{0.92} -Pb(I _{0.85} Br _{0.15}) ₃	10 ^{ap}	25 (5 × 5)	6	12.4	3.07	6.5	62	153
Spin coating	MAPbI ₃	22.4 ^{da}	25 (5 × 5)	6	12.03	3.38	5.8	61.3	154
Spin coating	[CsPbI ₃] _{0.05} [(FAPbI ₃) _{0.85} -(MAPbBr ₃) _{0.15}] _{0.95}	25 ^{da}	6.5 × 6.5	11	15.3	1.98	11.2	0.69	155
Bar coating	(FAPbI ₃) _{0.95} (MAPbBr ₃) _{0.05}	24.94 ^{da}	49 (7 × 7)	8	17.1 ^{da}	2.72 ^{da}	8.66	72.6	156
Spin coating/slot-die coating (SnO ₂)	CS _{0.05} (FA _{0.85} MA _{0.15}) _{0.95} -Pb(I _{0.85} Br _{0.15}) ₃	16.1 ^{ap}	30 (5 × 6)	6	15.2	3.28	6.7	69	157
Doctor blade coating	MAPbI ₃	100	176 (16 × 11)	9	4.3	7.5	9.6	53.8	158
Doctor blade coating	MAPbI ₃	11.1	24.2 (6.35 × 3.81)	4	14.1 (13.3 ^c)	~20.8	4.4	~61.5	159
Doctor blade coating	MAPbI ₃	33 ^{ap}	90 (6 × 15)	17	15 (15.3 ^c)	19.5	~18.2	72.1	160
Slot-die coating	MAPbI ₃	40	100 (10 × 10)	5	0.93	1.35	2.75	25	161
Slot-die coating	MAPbI ₃	17.6	25 (5 × 5)	8	10.6	3.25	6.14	53	162
Slot-die coating	MAPbI _{3-x} Cl _x	151.9	168.8 (12.5 × 13.5)	25	11.1	17.3	21.2	67.9	163
Screen printing	MA(5-AVA) _x (MA) _{1-x} PbI ₃	31	50 (5 × 10)	4	10.5	19.6	3.72	57.5	164
Screen printing	(5-AVA) _x (MA) _{1-x} PbI ₃	49	100 (10 × 10)	10	10.4	2	9.3	56	165
Screen printing	(5-AVA) _x (MA) _{1-x} PbI ₃	46.7	100 (10 × 10)	8	11.2	2.2	7.1	70.4	166
Screen printing	(5-AVA) _x (MA) _{1-x} PbI ₃	198 (435.6 ^{ap})	623.7 (21 × 29.7)	22	3.2	0.5	18.2	38.9	167
Spray coating	MAPbI _{3-x} Cl _x	40	100 (10 × 10)	10	15.5	2.1	10.5	70.2	168
Pressure processing method	MAPbI ₃	36.1 ^{ap}	64 (8 × 8)	10	15.7 (12.1 ^{CE})	2 (2 ^{CE})	10.5 (8.36 ^{CE})	75.7 (71.5 ^{CE})	169
HCVD	CS _{0.07} FA _{0.93} PbI ₃	12	25 (5 × 5)	6	14.6	3.67	5.84	0.681	170
CVD	CS _x FA _{1-x} PbI _{3-y} Br _y	41.25	64 (8 × 8)	—	12.24	2.25	9.18	52.8	171
HCVD	FAPb(I _{0.85} Br _{0.15}) ₃	12	25 (5 × 5)	6	14.7	3.55	6.29	0.66	172
HCVD	FAPbI ₃	12	25 (5 × 5)	6	9.0	2.97	5.64	0.54	173
HCVD	MAPbI _{3-x} Cl _x	15.4	25 (5 × 5)	6	5.8	2.53	4.62	0.49	173

^a The PCE and J_{sc} values are provided normalized by the active area unless otherwise stated: ap, aperture area; da, designated area (active area + dead area for interconnections). CE, certified efficiency; 5-AVA, 5-aminovaleric acid. ^b Normalized by active area. ^c Stabilized PCE.

compared with the values of PCEs for small-area spin coating PSCs method.

4. Perovskite solar module stability and degradation characterization

After obtaining the perovskite solar modules *via* different techniques and trying to improve the stability through understanding of the degradation mechanisms, it is not easy to confirm the stability and reliability of them toward the

commercial attainment of perovskite photovoltaic (PV) technology.^{174–177} On the whole, contemporary explanations have shown the prominence of the interfaces within the device that can enhance the devices efficiency as well as stability *via* incorporating suitable charge-transport layers and electrode materials with appropriate compositions. Auxiliary grasp should be given to the degradation processes of perovskite modules, which have low stability issues in order to confirm the importance of the interfaces and how it can change by time.¹⁷⁸

Different techniques are suitable for characterizing the stability of module scale with large-area perovskite materials



and stability that suppose as a significant shortcoming of PSCs. By reducing both the cost and energy consumption of resource extraction including material synthesis and film processing for the different components in PSCs as well as PSMs, it will result in decreasing the cost and environmental impact of the final PV modules.

6. Outlook and future perspectives

Many research directions are focused on large-scale perovskite modules to improve the fabrication techniques. However, these studies tried to optimize the ideal device architecture, but there are some drawbacks challenging the upscaling of perovskite solar cells such as the used materials, module interconnection as well as the processing challenges, including composition of perovskites. These compositions become more complex to control while conveying into the production scale and hence affect the cost of assembly, high efficiency and/or the stability of the modules. Take the price as well as environmental influence of the assembled PV modules down that will necessitate additional decreases in the cost and energy consumption of resource extraction, material preparation as well as film processing for several PSCs constituents.^{186–188} In addition, there are several characteristics that may enhance both the fabrication and the efficiency of the assembled modules as follows:

(1) The existence of FTO substrates with high conductivity is essential to overcome the possible series resistance that may be found while assembling the solar modules. In addition to that, we should keep the optical transmittance option in order to gain all the needed features for the fabricated modules.

(2) To optimize the assembled perovskite solar module design, several parameters should be taken into account such as the deposited layers as well as the active area of the module that should be enlarged, while at the same time, the mismatch loss and internal resistance should be reduced.

(3) The improvement of the auto production line is an essential step in the upscaling process, supporting unremitting and manageable fabrication process of the module. Additionally, in order to facilitate the fabrication of perovskite modules in terawatt large-scale with reasonable cost forming and life cycle assessments, the model architecture for the fabricated devices with scalable ingredients will be recognized.^{188–190} To conclude, because of the extraordinary advancement for

proficiency as well as long-term stability of PSCs, it is progressively necessary to think through the performance functions in the framework of scalability. It is yet precocious to understand the challenges of scaling up PSCs with reverence to the countless stacks and efficacious arrangements for module interconnection. Nonetheless, the quick progress on the way to scaling up at an appropriate performance side by side (efficiency and stability) together with the low industrialised charge competence has been previously involved in the worldwide industrial interest. The challenges for PSC scaling give a clear figure toward work requirements, which is versed by industries to ensure attaining high-efficiency and stability scalable modules.

Conflicts of interest

The author declare no conflict of interest.

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